

/ Descriptions

TO-220F NPN Silicon NPN transistor in a TO-220F Plastic Package.

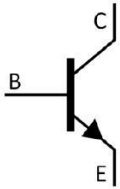
/ Features

High voltage, small collector output capacitance.

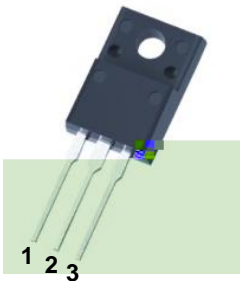
/ Applications

Color TV chroma output application.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

/ h_{FE} Classifications & Marking

See Marking Instructions.

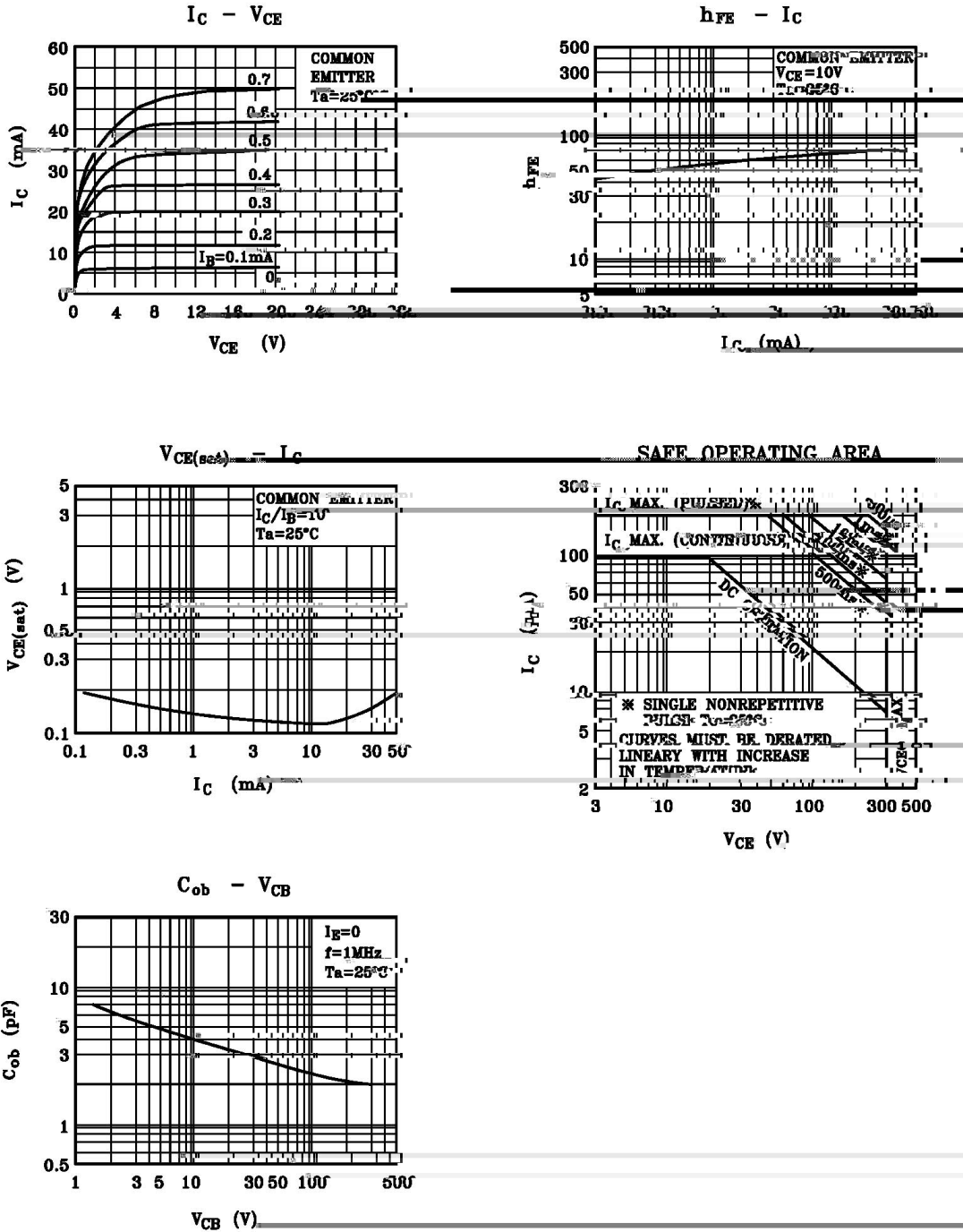
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	300	V
Collector to Emitter Voltage	V_{CE0}	300	V
Emitter to Base Voltage	V_{EBO}	5	V
Collector Current - Continuous	I_C	100	mA
Base Current	I_B	20	mA
Collector Power Dissipation	$P_C(T_C=25)$	2	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

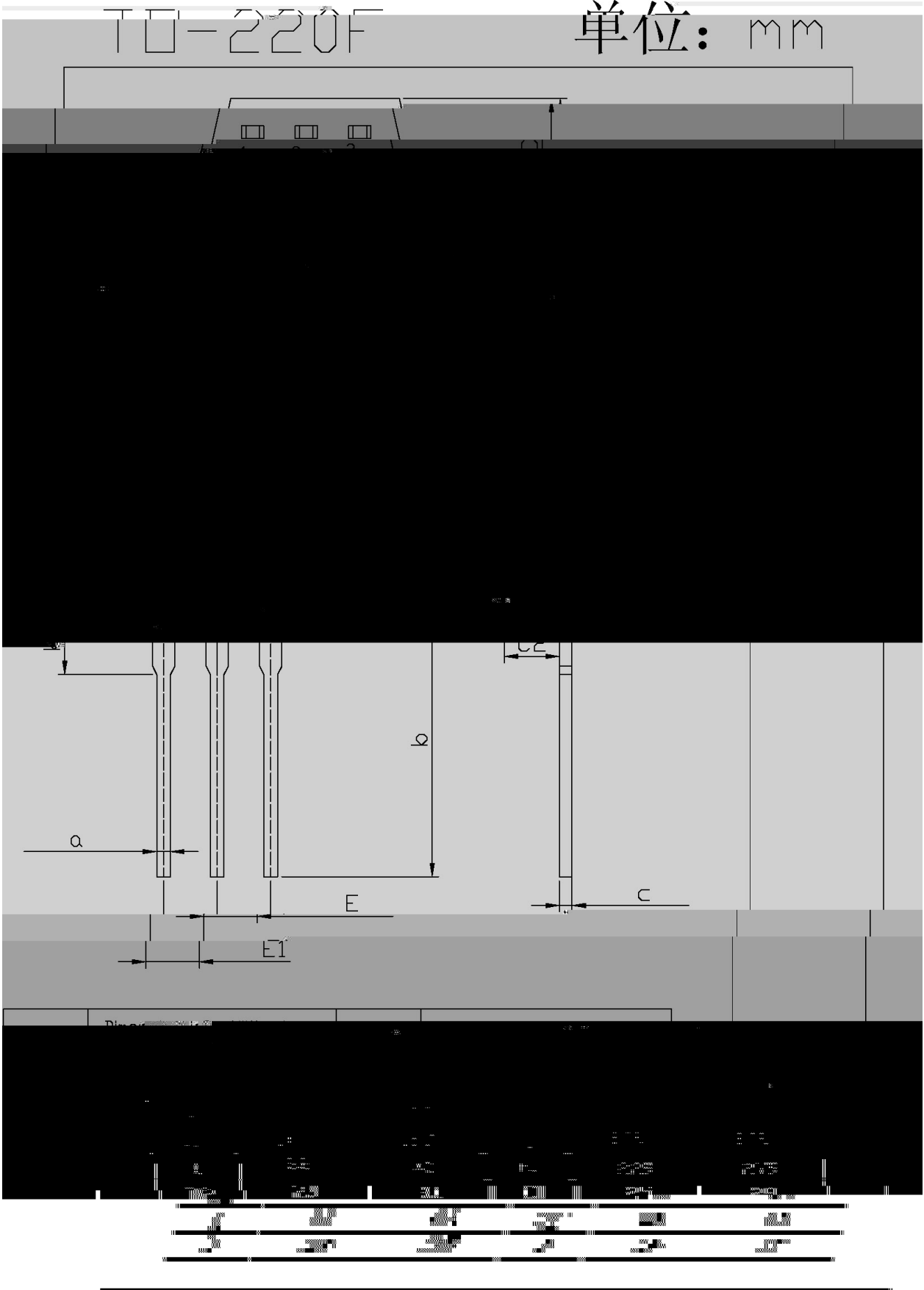
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=240V$ $I_E=0$			1	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=5V$ $I_C=0$			1	μA
DC Current Gain	$h_{FE(1)}$	$V_{CE}=10V$ $I_C=0.5mA$	20			
	$h_{FE(2)}$	$V_{CE}=10V$ $I_C=20mA$	30		200	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10mA$ $I_B=1mA$			1	V
Transition Frequency	f_T	$V_{CE}=20V$ $I_C=20mA$	75	95		MHz
Collector output capacitance	C_{ob}	$V_{CB}=20V$ $I_E=0$ $f=1MHz$		4		pF

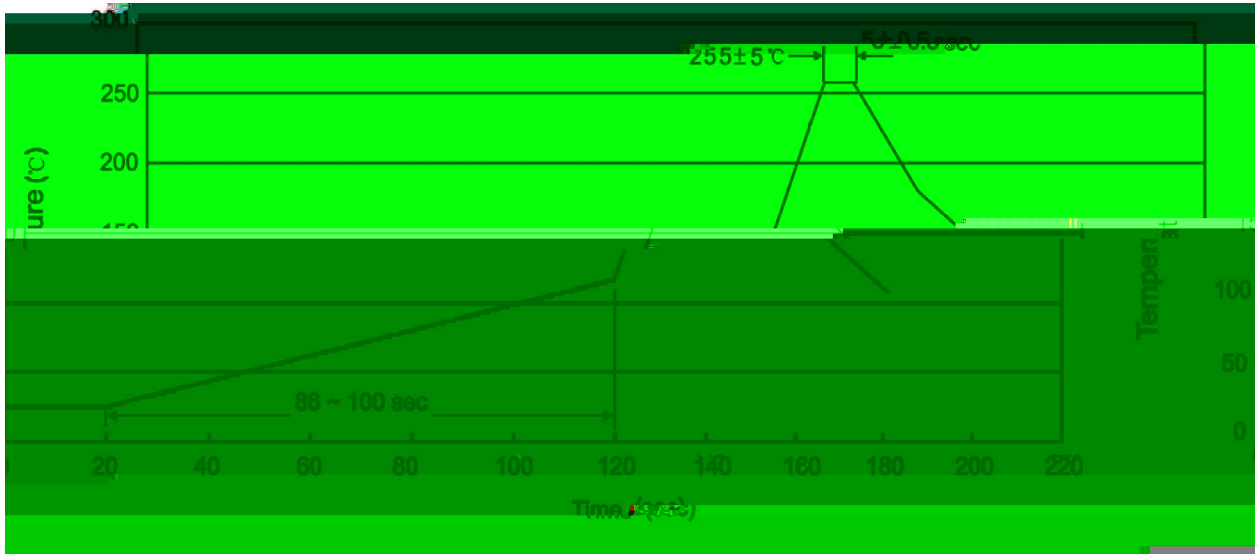
/ Electrical Characteristic Curve



/ Package Dimensions



() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|-------|----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255±5 | | 5±0.5 | sec; | 2.Peak Temp.:255±5 , Duration:5±0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type	Units				Dimension (unit mm3)		

/ TUBE

Package Type	Units				Dimension (unit mm3)		

/ Notices